

WEST[Help](#)[Logout](#)[Interrupt](#)[Main Menu](#)[Search Form](#)[Posting Counts](#)[Show 8 Numbers](#)[Edit 8 Numbers](#)[Preferences](#)[Cases](#)**Search Results -**

Terms	Documents
III-V near5 doped near2 oxygen	4

Database: US Patents Full-Text Database
US Pre-Grant Publication Full-Text Database
JPO Abstracts Database
EPO Abstracts Database
Derwent World Patents Index
IBM Technical Disclosure Bulletins

Search:

L41

[Refine Search](#)[Recall Text](#)[Clear](#)**Search History****DATE:** Monday, July 08, 2002 [Printable Copy](#) [Create Case](#)**Set Name Query**
side by side**Hit Count Set Name**
result set*DB=USPT; PLUR=YES; OP=ADJ*

L41	III-V near5 doped near2 oxygen	4	L41
L40	6392257.pn. and oxygen	1	L40
L39	oxygen doped near4 III-V	2	L39
L38	oxygen doped near2 III-V	2	L38
L37	silicon substrate near30 buffer layer and III-V	49	L37
L36	silicon substrate near20 buffer layer and oxygen doped	0	L36
L35	L34 and oxygen doped	0	L35
L34	srtio\$ near10 buffer layer	81	L34
L33	L31 and silicon near3 substrate	6	L33
L32	L31 and silicon near3 subsrate	0	L32

<u>L31</u>	light emitting and oxygen doped	41	<u>L31</u>
<u>L30</u>	(GaAs or Gallium Arsenide) near2 oxygen doped	3	<u>L30</u>
<u>L29</u>	oxygen doped near5 gaas	10	<u>L29</u>
<u>L28</u>	oxygen doped near5 ii-VI	0	<u>L28</u>
<u>L27</u>	oxygen doped near5 iii-v near3 semiconductor	1	<u>L27</u>
<u>L26</u>	oxygen doped near4 iii-v	2	<u>L26</u>
<u>L25</u>	oxygen doped near4 compound semiconductor	1	<u>L25</u>
<u>L24</u>	oxygen doped near2 compound semiconductor	0	<u>L24</u>
<u>L23</u>	oxygen doped near2 coupound semiconductor	0	<u>L23</u>
<u>L22</u>	silicon substrate and light emitting.ab. and oxide near4 buffer	3	<u>L22</u>
<u>L21</u>	(single crystal or monocrystalline) near5 oxygen doped	9	<u>L21</u>
<u>L20</u>	(single cyrstal or monocrystalline) near5 oxygen doped	3	<u>L20</u>
<u>L19</u>	(single cyrstal or monocrystalline) near2 oxygen doped near4 layer	0	<u>L19</u>
<u>L18</u>	L16 and oxygen doped	1	<u>L18</u>
<u>L17</u>	L16 and oxide near2 buffer	3	<u>L17</u>
<u>L16</u>	Buffer layer and iii-V and silicon substrate and light emitting	83	<u>L16</u>
<u>L15</u>	Buffer layer and iii-V and silicon substrate	226	<u>L15</u>
<u>L14</u>	oxide near2 buffer layer and light emitting	12	<u>L14</u>
<u>L13</u>	silicon substrate and oxide near2 buffer layer and light emitting	4	<u>L13</u>
<u>L12</u>	silicon substrate.clm. and oxide near2 buffer layer.clm.	13	<u>L12</u>
<u>L11</u>	silicon substate.clm. and oxide near2 buffer layer.clm.	0	<u>L11</u>
<u>L10</u>	silicon substate.clm. and oxide near2 buffer layer.clm.	0	<u>L10</u>
<u>L9</u>	light emitting and silicon substrate and Oxygen doped and buffer layer	1	<u>L9</u>
<u>L8</u>	6143072.pn.	1	<u>L8</u>
<u>L7</u>	6173474.pn.	1	<u>L7</u>
<u>L6</u>	6174755.pn.	1	<u>L6</u>
<u>L5</u>	6180486.pn.	1	<u>L5</u>
<u>L4</u>	light emitting and silicon substrate and oxygen doped near2 III-V	0	<u>L4</u>
<u>L3</u>	iii-V near20 buffer layer near30 silicon substrate	1	<u>L3</u>
<u>L2</u>	silicon substrate near20 accommodating buffer	2	<u>L2</u>
<u>L1</u>	silicon substrate near20 accomodating buffer	0	<u>L1</u>

END OF SEARCH HISTORY